## NSN 5962-01-381-4167

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-381-4167 **Body Length:** 1.490 inches **Body Width:** 0.610 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and programmed and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 15 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Current Rating Per Characteristic:** 55.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 6.5 volts power source **Capitance Rating Per Characteristic:** 12.00 input picofarads and 14.00 output picofarads **Time Rating Per Chacteristic:** 120.00 nanoseconds access

#### **Memory Device Type:**

**Eprom** 

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

28 printed circuit

### Shelf Life:

N/a

# NSN 5962-01-381-4167

Memory Microcircuit - Page 2 of 2



**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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